

2.5V CLOCK BUFFER

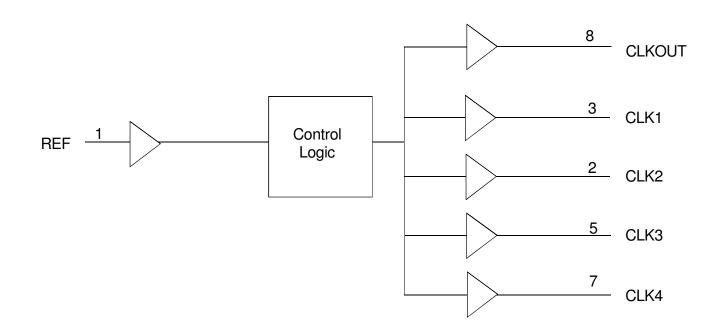
FEATURES:

- Clock Distribution
- 10MHz to 133MHz operating frequency
- · Distributes one clock input to one bank of five outputs
- Output Skew < 250ps
- No external RC network required
- Operates at 2.5V VDD
- Available in SOIC package
- · Available in commercial and industrial temperature range

DESCRIPTION:

The IDT2305NZT is a high-speed clock buffer, designed to address high-speed clock distribution applications. IDT2305NZT accepts one reference input, and drives out five low skew clocks.

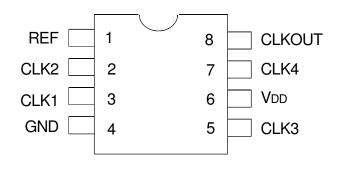
FUNCTIONAL BLOCK DIAGRAM



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INDUSTRIAL TEMPERATURE RANGE

PIN CONFIGURATION



SOIC TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Max.	Unit
Vdd	Supply Voltage Range	-0.5 to +4.6	V
VI ⁽²⁾	Input Voltage Range (REF)	-0.5 to +5.5	V
Vi	Input Voltage Range	-0.5 to	V
	(except REF)	VDD+0.5	
Iк (VI < 0)	Input Clamp Current	-50	mA
Io (Vo = 0 to VDD)	Continuous Output Current	±50	mA
VDD or GND	Continuous Current	±100	mA
TA = 55°C	Maximum Power Dissipation	0.7	W
(in still air) ⁽³⁾			
Tstg	Storage Temperature Range	-65 to +150	°C
Operating	Industrial Temperature	-40 to +85	°C
Temperature	Range		

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

APPLICATIONS:

- SDRAM
- Telecom
- Datacom
- PC Motherboards/Workstations
- · Critical Path Delay Designs

PIN DESCRIPTION

Pin Name	Pin Number	Туре	Functional Description
REF ⁽¹⁾	1	IN	Input reference clock, 3.3V tolerant input
CLK2 ⁽²⁾	2	OUT	Output clock
CLK1 ⁽²⁾	3	OUT	Output clock
GND	4	GND	Ground
CLK3 ⁽²⁾	5	OUT	Output clock
Vdd	6	PWR	2.5V Supply
CLK4 ⁽²⁾	7	OUT	Output clock
CLKOUT ⁽²⁾	8	OUT	Output clock

NOTES:

1. Weak pull down.

2. Weak pull down on all outputs.

OPERATING CONDITIONS

Symbol	Parameter		Max.	Unit
Vdd	Supply Voltage	2.3	2.7	V
TA	Operating Temperature (Ambient Temperature)	-40	+85	°C
CL	Load Capacitance 10MHz - 133MHz	—	15	pF
CIN	InputCapacitance	—	7	pF

DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Max.	Unit
VIL	Input LOW Voltage Level		—	0.7	V
Vih	Input HIGH Voltage Level		1.7	—	V
١L	Input LOW Current	VIN = 0V	—	50	μA
Ін	Input HIGH Current	VIN = VDD	—	100	μA
Vol	Output LOW Voltage	Standard Drive, IoL = 8mA	—	0.3	V
Vон	Output HIGH Voltage	Standard Drive, Іон = -8mA	2	—	V
IDD_PD	Power Down Current	REF = 0MHz	—	12	μA
IDD	Supply Current	Unloaded Outputs at 66.66MHz	_	32	mA

SWITCHING CHARACTERISTICS^(1,2)

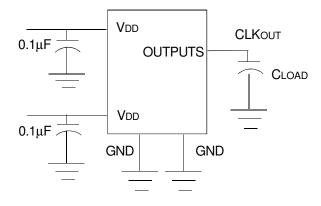
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
tı	Output Frequency	15pFLoad	10	_	133	MHz
	Duty Cycle = t2 ÷ t1	Measured at VDD/2, FOUT = 66.66MHz	40	50	60	%
t3	RiseTime	Measured between 0.7V and 1.7V	_	_	2.5	ns
t4	FallTime	Measured between 0.7V and 1.7V	_	_	2.5	ns
ts	Output to Output Skew	All outputs equally loaded	-	_	250	ps
t6	Delay, REF Rising Edge to CLKOUT Rising Edge	Measured at VDD/2	-	0	8.7	ns
tz	Device-to-Device Skew	Measured at VDD/2 on the CLKOUT pins of devices	_	0	700	ps

NOTES:

1. REF Input has a threshold voltage of VDD/2.

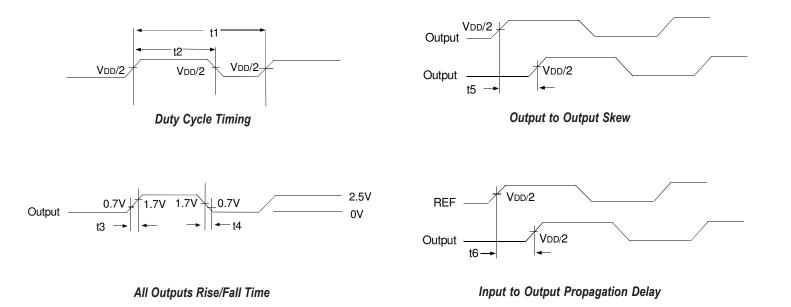
2. All parameters specified with loaded outputs.

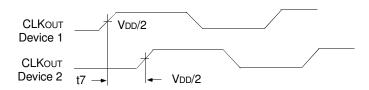
TEST CIRCUIT



Test Circuit for All Parameters

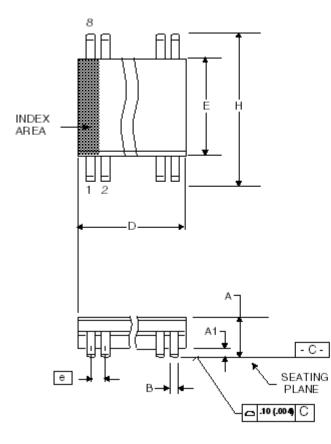
SWITCHING WAVEFORMS



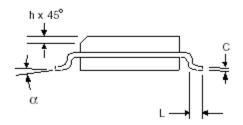


Device to Device Skew

Package Outline and Package Dimensions (8-pin SOIC, 150 Mil. Body)



	Millimeters	S	Inches	
Symbol	Min	Max	Min	Max
А	1.35	1.75	0.0532	0.0688
A1	0.1	0.25	0.004	0.0098
В	0.33	0.51	0.013	0.02
С	0.19	0.25	0.0075	0.0098
D	4.8	5	0.189	0.1968
E	3.8	4	0.1497	0.1574
е	1.27 BASIC		0.050	BASIC
Н	5.8	6.2	0.2284	0.244
h	0.25	0.5	0.01	0.02
Ĺ	0.4	1.27	0.016	0.05
а	0°	8°	0°	8°



Ordering Information

Part / Order Number	Shipping Packaging	Package	Temperature
2305NZT-1DCG	Tubes	8-pin SOIC	0 to +70° C
2305NZT-1DCG8	Tape and Reel	8-pin SOIC	0 to +70° C
2305NZT-1DCGI	Tubes	8-pin SOIC	-40 to +85° C
2305NZT-1DCGI8	Tape and Reel	8-pin SOIC	-40 to +85°C

"G" after the two-letter package code denotes Pb free configuration, RoHS complaint.

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